

### VS-VSKD600..PbF

Vishay Semiconductors

# Standard Diodes (Super MAGN-A-PAK Power Modules), 600 A



Super MAGN-A-PAK

PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub> 600 A				
Туре	Modules - diode, high voltage			
Package	Super MAGN-A-PAK			
Circuit configuration	Two diodes doubler circuit			

#### **FEATURES**

- High current capability
- High surge capability
- High voltage ratings up to 2000 V
- 3000 V<sub>RMS</sub> isolating voltage with non-toxic substrate
- Industrial standard package
- UL approved file E78996
  - 6 74
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

#### **TYPICAL APPLICATIONS**

- Rectifying bridge for large motor drives
- · Rectifying bridge for large UPS

MAJOR RATINGS AND CHARACTERISTICS				
SYMBOL	CHARACTERISTICS	VALUES	UNITS	
1		600	A	
I <sub>F(AV)</sub>	T <sub>C</sub>	100	°C	
1		942	A	
I <sub>F</sub> (RMS)	T <sub>C</sub>	100	°C	
1	50 Hz	19 000	Δ.	
I <sub>FSM</sub>	60 Hz	20 100	A	
l <sup>2</sup> t	50 Hz	1805	kA <sup>2</sup> s	
1-1	60 Hz	1683	KA-S	
I²√t		18 050	kA²√s	
V <sub>RRM</sub>	Range	800 to 2000	V	
T <sub>Stg</sub> , T <sub>J</sub>	Range	-40 to +150	°C	

#### **ELECTRICAL SPECIFICATIONS**

VOLTAGE RATINGS						
TYPE NUMBER	VOLTAGE CODE	V <sub>RRM</sub> , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I <sub>RRM</sub> MAXIMUM AT T <sub>J</sub> MAXIMUM mA		
	08	800	900			
VS-VSKD600		1200	1300	50		
v3-v3RD000	16	1600	1700	50		
	20	2000	2100			



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FORWARD CONDUCTION						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum average forward current		100° condi	180° conduction, half sine wave		600	Α
at case temperature	I <sub>F(AV)</sub>	160 Condi	uction, nail sine	e wave	100	°C
Maximum RMS forward current	I <sub>F(RMS)</sub>	180° condi	uction, half sine	wave at T <sub>C</sub> = 100 °C	942	Α
		t = 10 ms	No voltage	Sinusoidal half wave,	19.0	- kA
Maximum peak, one-cycle forward,		t = 8.3 ms	reapplied		20.1	
non-repetitive surge current	I <sub>FSM</sub>	t = 10 ms	100 % V <sub>RRM</sub>		16.2	
		t = 8.3 ms	reapplied		17.2	
10.6		t = 10 ms	No voltage	initial $T_J = T_J$ maximum	1805	
	l <sup>2</sup> t	t = 8.3 ms	reapplied		1683	- kA <sup>2</sup> s
Maximum I <sup>2</sup> t for fusing		t = 10 ms	100 % V <sub>RRM</sub>		1319	
		t = 8.3 ms	reapplied		1230	
Maximum I <sup>2</sup> √t for fusing	I <sup>2</sup> √t	t = 0.1 ms to 10 ms, no voltage reapplied		18 050	kA²√s	
Low level value of threshold voltage	V <sub>F(TO)1</sub>	(16.7 % x $\pi$ x $I_{F(AV)}$ < I < $\pi$ x $I_{F(AV)}$ ), $T_J = T_J$ maximum		0.70	V	
High level value of threshold voltage	V <sub>F(TO)2</sub>	$(I > \pi \times I_{F(AV)}), T_J = T_J \text{ maximum}$		0.77	7 V	
Low level value of forward slope resistance	r <sub>f1</sub>	(16.7 % x $\pi$ x $I_{F(AV)}$ < I < $\pi$ x $I_{F(AV)}$ ), $T_J = T_J$ maximum		0.28		
High level value of forward slope resistance	r <sub>f2</sub>	$(I > \pi \times I_{F(AV)}), T_J = T_J \text{ maximum}$		0.25	mΩ	
Maximum forward voltage drop	$V_{FM}$	$I_{pk} = 1800 \text{ A}, T_J = 25 \text{ °C}, t_p = 10 \text{ ms sine pulse}$		1.45	V	

BLOCKING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
RMS insulation voltage	V <sub>INS</sub>	t = 1 s	3000	V
Maximum peak reverse and off-state leakage current	I <sub>RRM</sub>	$T_J = T_J$ maximum, rated $V_{RRM}$ applied	50	mA

THERMAL AND MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction operating and storage temperature range			-40 to +150	°C
Maximum thermal resistance, junction to case per junction	R <sub>thJC</sub>	DC operation	0.065	K/W
Maximum thermal resistance, case to heatsink per module	R <sub>thC-hs</sub>	Mounting surface smooth, flat and greased	0.02	N VV
		A mounting compound is recommended and the	6 to 8	
torque ± 10 % busbar to Super MAGN-A-PAK		torque should be rechecked after a period of 3 hours to allow for the spread of the compound		Nm
Approximate weight			1500	g
Case style		See dimensions - link at the end of datasheet	Super MAGN	I-A-PAK

△R <sub>thJC</sub> CONDUCTION					
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS	
180°	0.009	0.006			
120°	0.011	0.011			
90°	0.014	0.015	$T_J = T_J \text{ maximum}$	K/W	
60°	0.021	0.022			
30°	0.037	0.038			

#### Note

• The table above shows the increment of thermal resistance RthJC when devices operate at different conduction angles than DC

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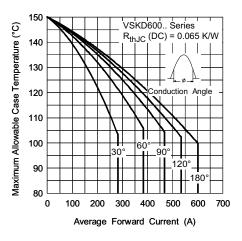


Fig. 1 - Current Ratings Characteristics

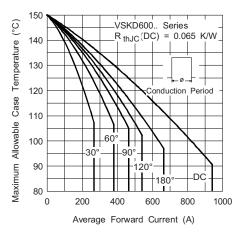


Fig. 2 - Current Ratings Characteristics

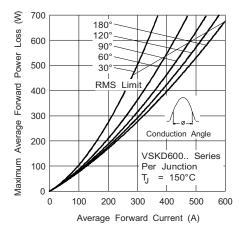


Fig. 3 - Forward Power Loss Characteristics

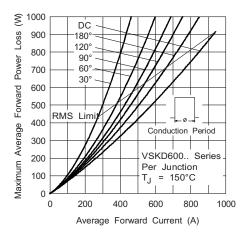


Fig. 4 - Forward Power Loss Characteristics

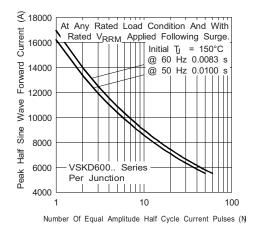


Fig. 5 - Maximum Non-Repetitive Surge Current

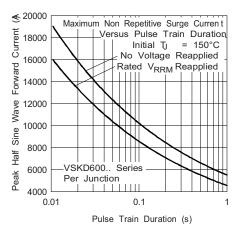


Fig. 6 - Maximum Non-Repetitive Surge Current

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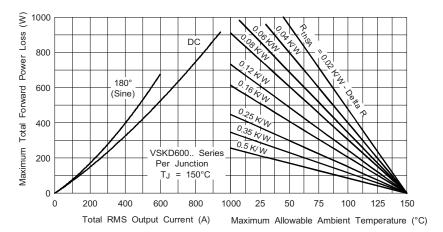


Fig. 7 - Forward Power Loss Characteristics

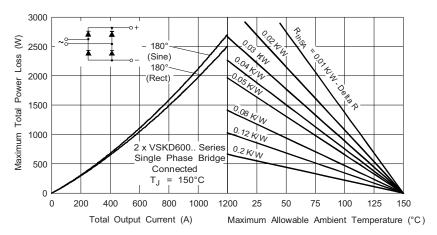


Fig. 8 - Forward Power Loss Characteristics

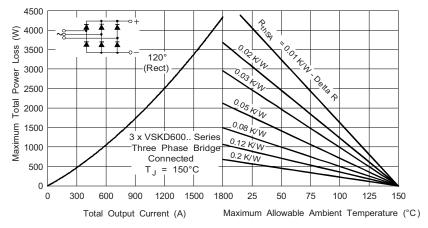


Fig. 9 - Forward Power Loss Characteristics



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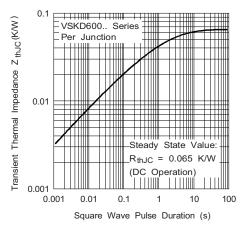
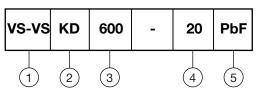


Fig. 10 - Thermal Impedance Z<sub>thJC</sub> Characteristic

#### **ORDERING INFORMATION TABLE**

Device code



- Vishay Semiconductors product
- Circuit configuration D = two diodes in series
  (see circuit configuration table)
- 3 Current rating
- Voltage code x 100 = V<sub>RRM</sub> (see voltage ratings table)
- 5 Lead (Pb)-free

CIRCUIT CONFIGURATION				
CIRCUIT DESCRIPTION	CIRCUIT CONFIGURATION CODE	CIRCUIT DRAWING		
Two diodes doubler circuit	KD	3 Q Q Q Q Q Q Q Q Q Q Q Q Q Q Q Q Q Q Q		

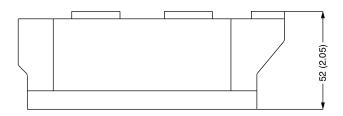
LINKS TO RELATED DOCUMENTS		
Dimensions	www.vishay.com/doc?95088	



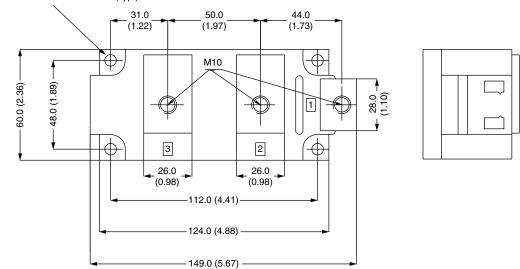
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## **Super MAGN-A-PAK Diode**

#### **DIMENSIONS** in millimeters (inches)



 $\emptyset$  6.5 mm  $\pm$  0.3 mm x 4 Holes (Typ.)

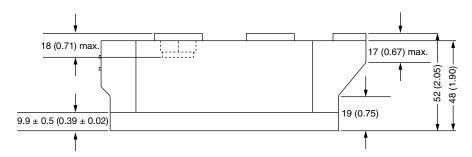


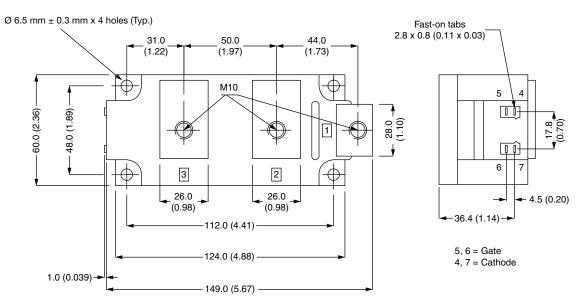


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# **Super MAGN-A-PAK Thyristor/Diode**

#### **DIMENSIONS** in millimeters (inches)







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